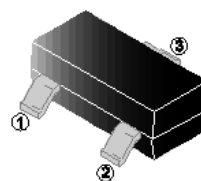


RoHS Compliant Product  
A Suffix of "-C" specifies halogen & lead-free

## FEATURES

- Surface Mount Package
- High Density Cell Design for Extremely Low  $R_{DS(ON)}$
- Voltage Controlled Small Signal Switch

**SOT-23**



## APPLICATION

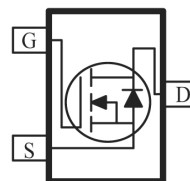
- Small Servo Motor Controls
- Power MOSFET Gate Drivers
- Switching Application

## MARKING

**B123**

## PACKAGE INFORMATION

Package	MPQ	Leader Size
SOT-23	3K	7 inch



## ORDER INFORMATION

Part Number	Type
SMS123J-C	Lead (Pb)-free and Halogen-free

## MAXIMUM RATINGS ( $T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	$V_{DS}$	100	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current <sup>1</sup>	$I_D$	0.17	A
Pulsed Drain Current @ $t_p=10\mu\text{s}$	$I_{DM}$	0.68	A
Continuous Source-Drain Diode Current	$I_S$	0.17	A
Power Dissipation	$P_D$	0.35	W
Thermal Resistance from Junction-Ambient <sup>1</sup>	$R_{\theta JA}$	357	$^\circ\text{C/W}$
Lead Temperature for Soldering Purposes (1/8" from case for 10s)	$T_L$	260	$^\circ\text{C}$
Operating Junction & Storage Temperature Range	$T_J, T_{STG}$	150, -55~150	

**ELECTRICAL CHARACTERISTICS** ( $T_A=25^\circ\text{C}$  unless otherwise specified)

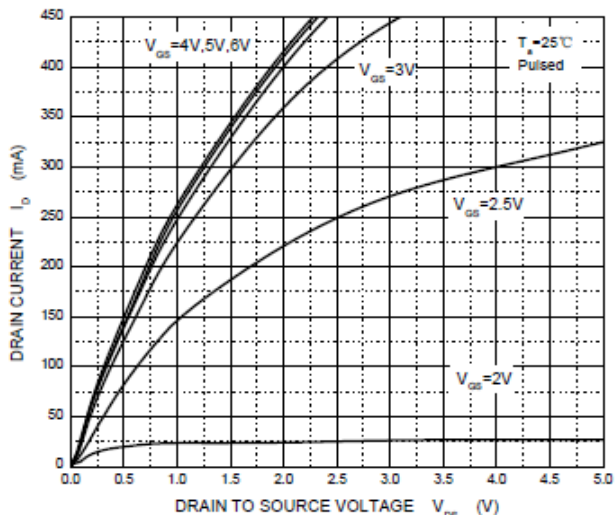
Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	100	-	-	V	$V_{GS}=0V, I_D=250\mu A$
Gate-Threshold Voltage <sup>2</sup>	$V_{GS(th)}$	1	-	2	V	$V_{DS}=V_{GS}, I_D=250\mu A$
Forward Transfer Conductance <sup>2</sup>	$g_{fs}$	80	-	-	mS	$V_{DS}=10V, I_D=0.17A$
Zero Gate Voltage Drain Current	$I_{DSS}$	-	-	1	$\mu A$	$V_{DS}=100V, V_{GS}=0V$
		-	-	10	nA	$V_{DS}=20V, V_{GS}=0V$
Gate-Source Leakage	$I_{GSS}$	-	-	$\pm 50$	nA	$V_{DS}=0V, V_{GS}=\pm 20V$
Drain-Source On Resistance <sup>2</sup>	$R_{DS(ON)}$	-	3.5	6	$\Omega$	$V_{GS}=10V, I_D=0.17A$
		-	3.8	10		$V_{GS}=4.5V, I_D=0.17A$
Total Gate Charge	$Q_g$	-	1.4	-	nC	$V_{DS}=10V$ $V_{GS}=10V$ $I_D=0.22A$
Gate-to-Source Charge	$Q_{gs}$	-	0.15	-		
Gate-to-Drain Charge	$Q_{gd}$	-	0.2	-		
Turn-on Delay Time	$T_{d(on)}$	-	8	-	nS	$V_{DD}=30V$ $I_D=0.28A$ $V_{GS}=10V$ $R_{GEN}=50\Omega$
Rise Time	$T_r$	-	8	-		
Turn-off Delay Time	$T_{d(off)}$	-	13	-		
Fall Time	$T_f$	-	16	-		
Input Capacitance	$C_{iss}$	-	29	-	pF	$V_{DS}=25V$ $V_{GS}=0V$ $f=1MHz$
Output Capacitance	$C_{oss}$	-	10	-		
Reverse Transfer Capacitance	$C_{rss}$	-	2	-		
<b>Source-Drain Diode</b>						
Diode Forward On-Voltage	$V_{SD}$	-	-	1.3	V	$I_S=340mA, V_{GS}=0V$

Notes:

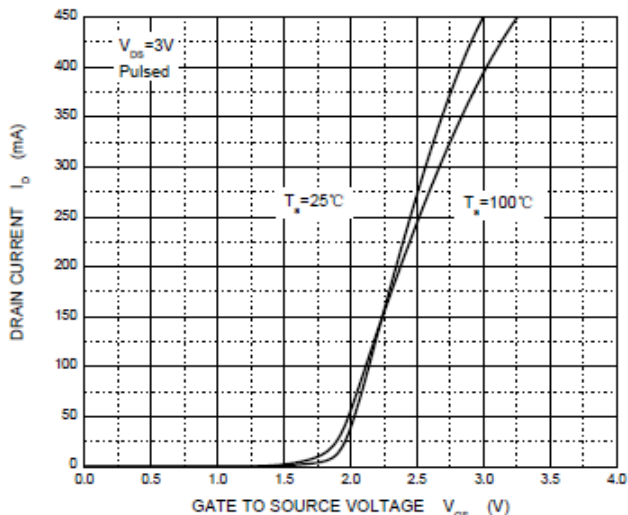
1. Surface mounted on FR-4 Board using the minimum recommended pad size.
2. Pulse Test: Pulse width=300 $\mu s$ , duty cycle  $\leq 2\%$ .
3. Switching characteristics are independent of operating junction temperature.

**CHARACTERISTIC CURVES**

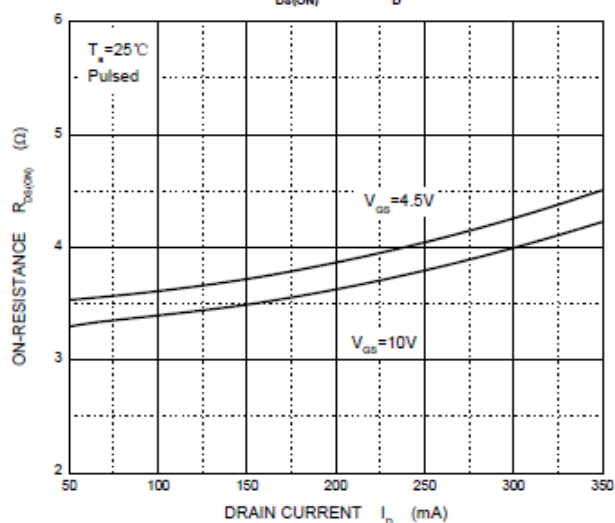
Output Characteristics



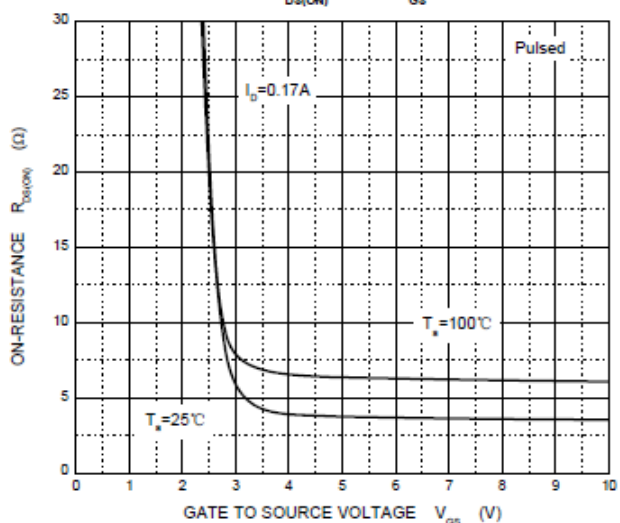
Transfer Characteristics



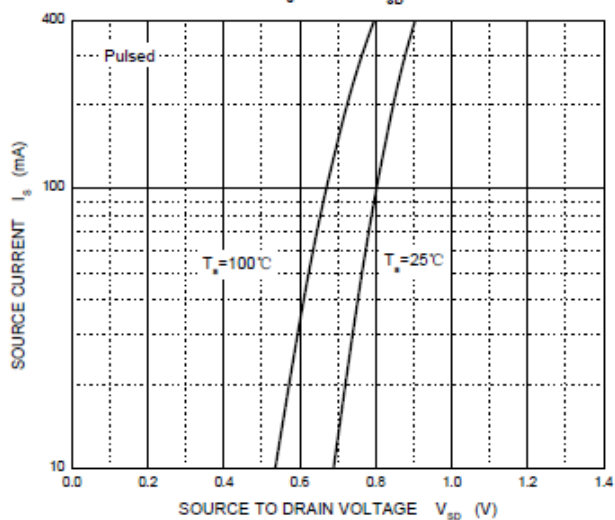
$R_{DS(ON)}$  —  $I_D$



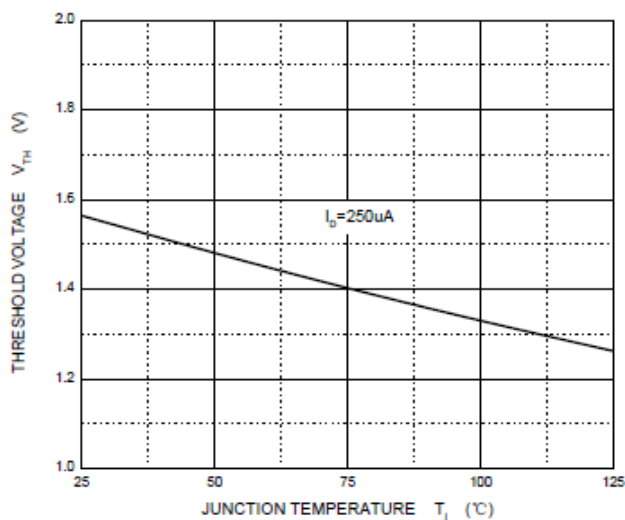
$R_{DS(ON)}$  —  $V_{GS}$



$I_S$  —  $V_{SD}$

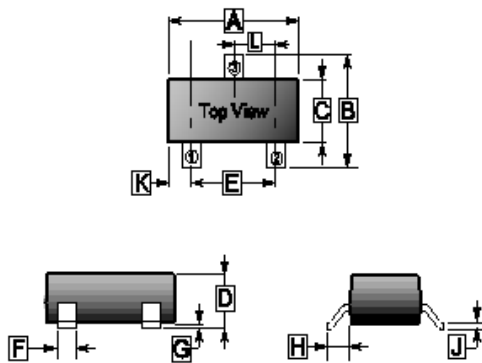


Threshold Voltage



**PACKAGE OUTLINE DIMENSIONS**

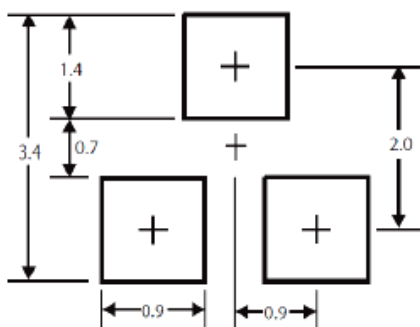
**SOT-23**



REF.	Millimeter	
	Min.	Max.
A	2.65	3.10
B	2.10	3.00
C	1.10	1.80
D	0.89	1.40
E	1.70	2.30
F	0.28	0.55
G	0	0.18
H	0.55 REF.	
J	0.05	0.26
K	0.60 REF.	
L	0.95 TYP.	

**MOUNTING PAD LAYOUT**

**SOT-23**



\*Dimensions in millimeters